



High voltage fast-switching NPN power transistor

Datasheet — production data

Features

- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Switch mode power supplies

Description

This device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.

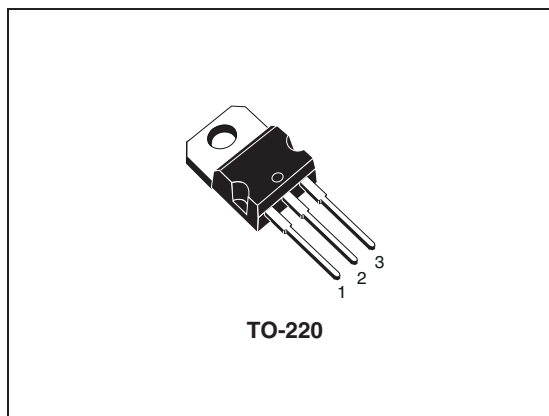


Figure 1. Internal schematic diagram

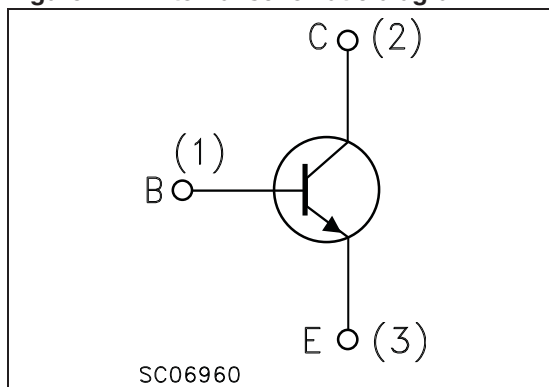


Table 1. Device summary

Order code	Marking ⁽¹⁾	Package	Packaging
ST13005	13005 A 13005 C 13005 D 13005 E 13005 F	TO-220	Tube

1. Product is pre-selected in DC current gain (group A, C, D, E and F). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	9	V
I_C	Collector current	4	A
I_{CM}	Collector peak current ($t_P < 5$ ms)	8	A
I_B	Base current	2	A
I_{BM}	Base peak current ($t_P < 5$ ms)	4	A
P_{TOT}	Total dissipation at $T_C \leq 25$ °C	75	W
T_{STG}	Storage temperature	- 65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case max	1.7	°C/W
$R_{thj-amb}$	Thermal resistance junction-amb max	62.5	°C/W

2 Electrical characteristics

$T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = 700\text{ V}$ $V_{\text{CE}} = 700\text{ V } T_{\text{C}} = 125\text{ }^{\circ}\text{C}$			1 5	mA mA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 9\text{ V}$			1	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 10\text{ mA}$	400			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 0.2\text{ A}$ $I_{\text{C}} = 2\text{ A}$ $I_{\text{B}} = 0.5\text{ A}$ $I_{\text{C}} = 4\text{ A}$ $I_{\text{B}} = 1\text{ A}$			0.5 0.6 1	V V V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 0.2\text{ A}$ $I_{\text{C}} = 2\text{ A}$ $I_{\text{B}} = 0.5\text{ A}$			1.2 1.6	V V
$h_{\text{FE}}^{(1)(2)}$	DC current gain	$I_{\text{C}} = 1\text{ A}$ $V_{\text{CE}} = 5\text{ V}$ Group A Group C Group D Group E Group F $I_{\text{C}} = 2\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	15 16 21 26 31 8		32 22 27 32 37 40	
t_{s} t_{f}	Resistive load Storage time Fall time	$I_{\text{C}} = 2\text{ A}$ $V_{\text{CC}} = 125\text{ V}$ $I_{\text{B1}} = -I_{\text{B2}} = 0.4\text{ A}$ $t_{\text{p}} = 30\text{ }\mu\text{s}$	1.5	0.2	3	μs μs

1. Pulse test: pulse duration = 300 μs , duty cycle $\leq 2\%$.

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2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

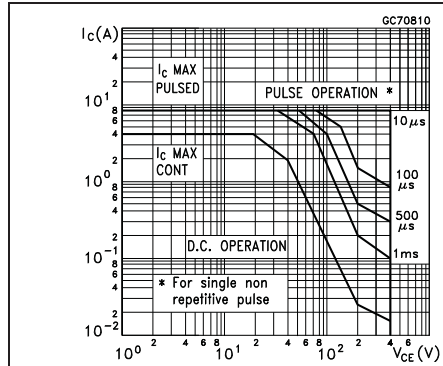


Figure 3. Derating curve

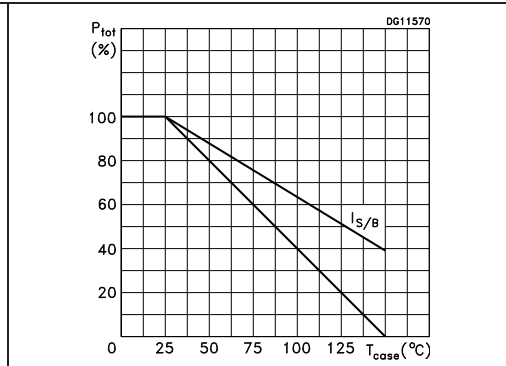
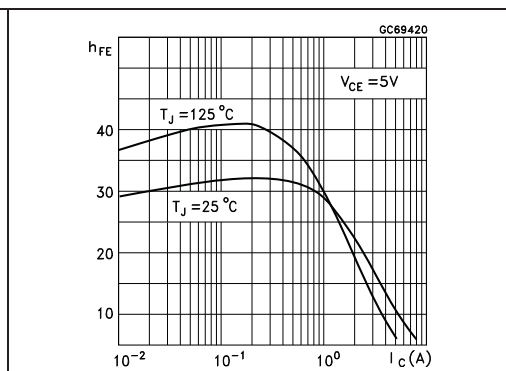
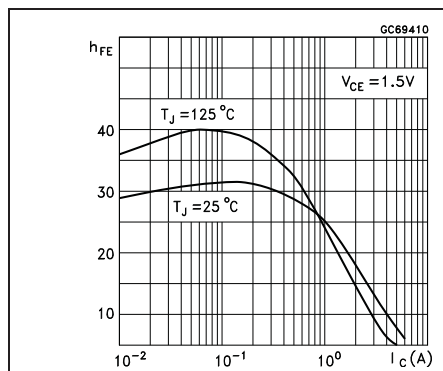
Figure 4. DC current gain ($V_{CE} = 1.5$ V) Figure 5. DC current gain ($V_{CE} = 5$ V)

Figure 6. Collector-emitter saturation voltage

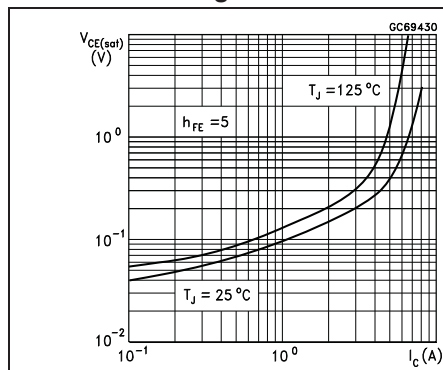


Figure 7. Base-emitter saturation voltage

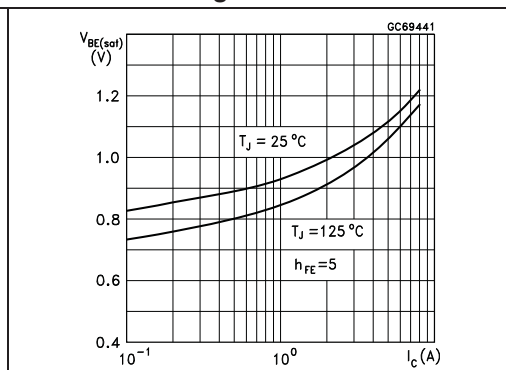
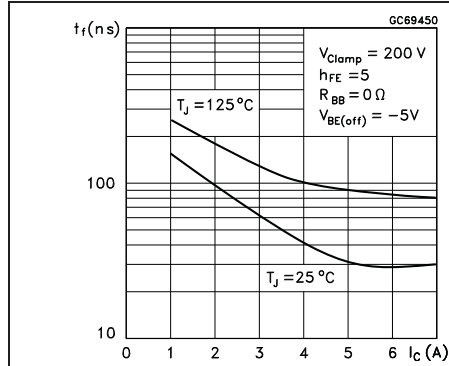
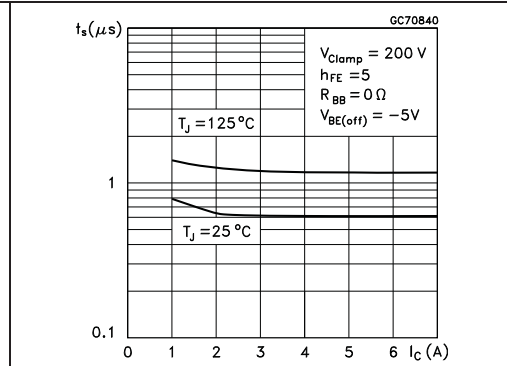
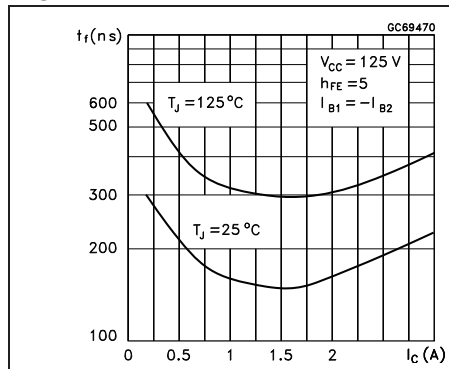
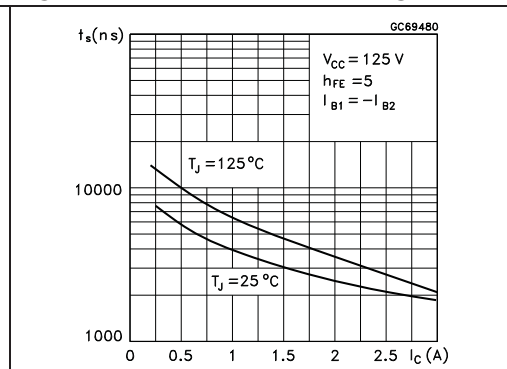
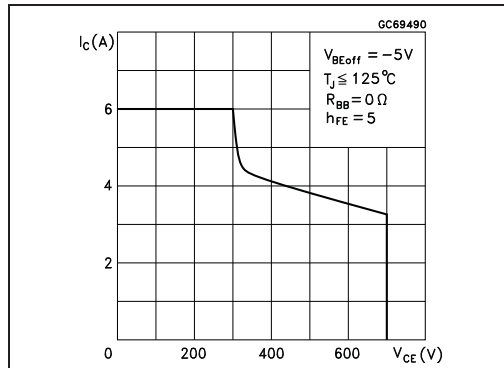


Figure 8. Inductive load fall time**Figure 9. Inductive load storage time****Figure 10. Resistive load fall time****Figure 11. Resistive load storage time****Figure 12. Reverse biased safe operating area**

2.2 Test circuits

Figure 13. Inductive load switching test circuit

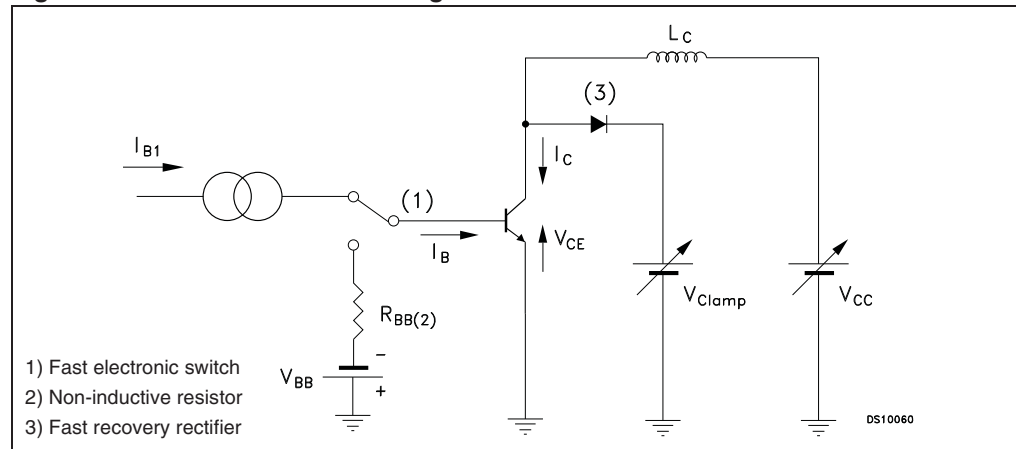
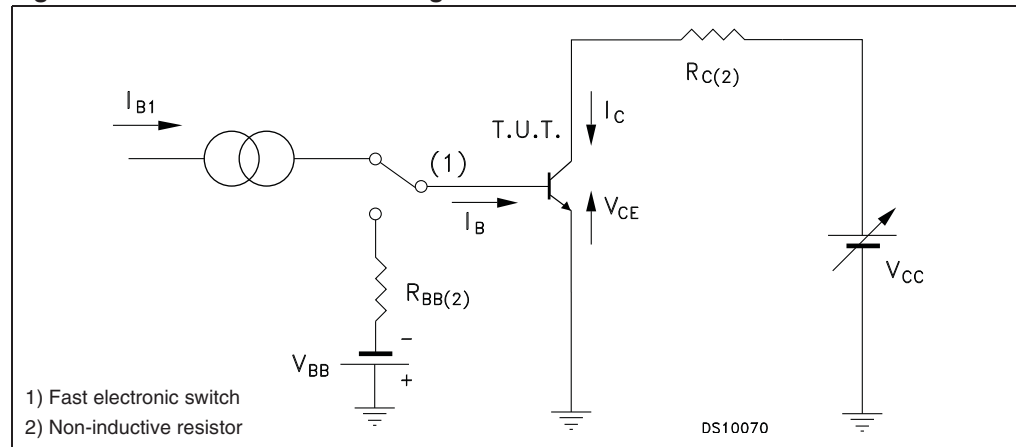


Figure 14. Resistive load switching test circuit



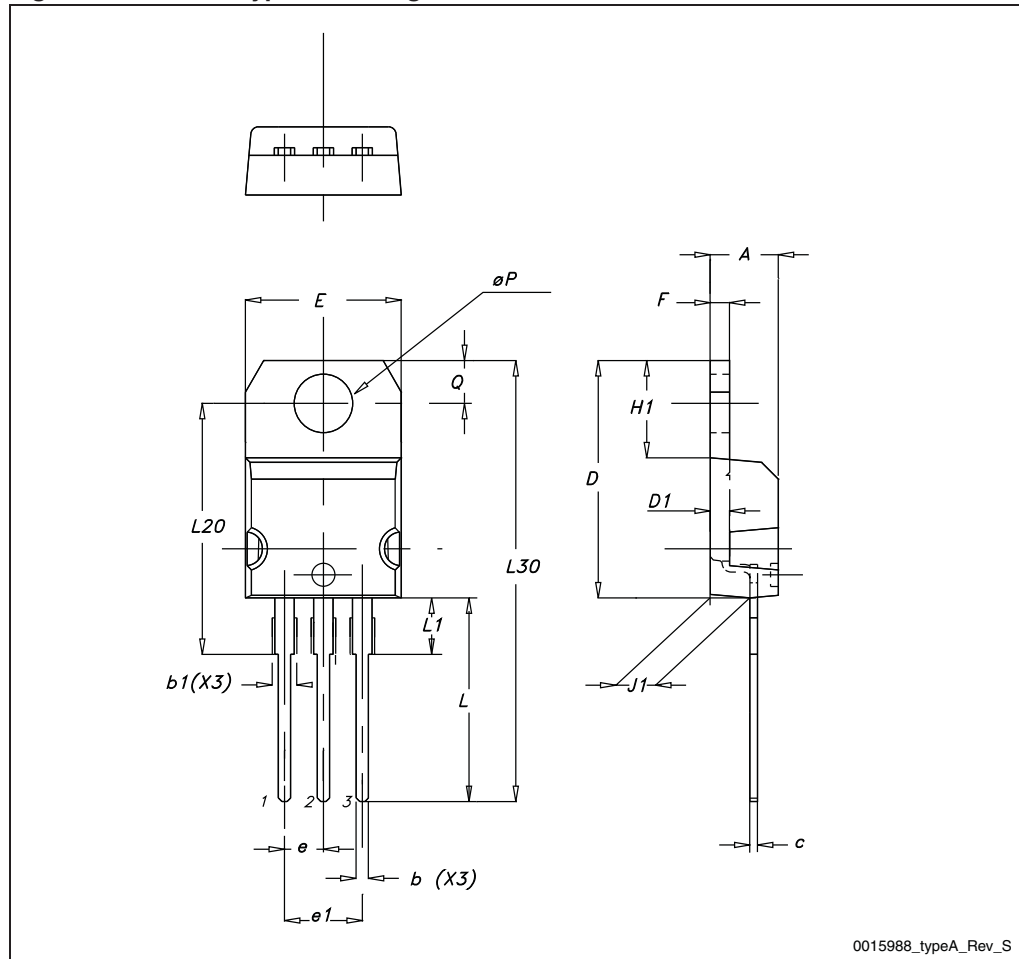
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. TO-220 type A mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

Figure 15. TO-220 type A drawing



4 Revision history

Table 6. Document revision history

Date	Revision	Changes
21-Jun-2004	6	
22-Aug-2007	7	Updated mechanical data according to PCN APM-PWR/07/2804
12-Oct-2007	8	Updated marking in Table 1
15-Feb-2012	9	– Updated marking in Table 1 – Inserted: Table 3 – Modified: h_{FE} in Table 4 – Updated mechanical data
15-May-2012	10	Updated marking in Table 1 and 4

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